## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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TRANSISTOR STRUCTURE HAVING REDUCED TRANSISTOR LEAKAGE

**ATTRIBUTES** 

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MS Amendment

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

We are transmitting herewith the following attached items (as indicated with an "X"):

Return postcard.

Amendment and Response (18 pgs.).

Supplemental Information Disclosure Statement (2 pgs.), Form 1449 (1 pg.).

Check in the amount of \$180.00 to cover the fee for consideration of Information Disclosure Statement under 97(c).

If not provided for in a separate paper filed herewith, Please consider this a PETITION FOR EXTENSION OF TIME for sufficient number of months to enter these papers and please charge any additional fees or credit overpayment to Deposit Account No. 19-0743.

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